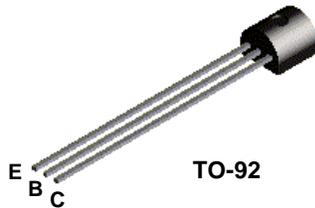




## BCX79



### PNP General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 300 mA. Sourced from Process 68. See PN200A for characteristics.

#### Absolute Maximum Ratings\*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	45	V
V <sub>CES</sub>	Collector-Base Voltage	45	V
V <sub>EBO</sub>	Emitter-Base Voltage	5.0	V
I <sub>C</sub>	Collector Current - Continuous	500	mA
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

#### Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		BCX79	
P <sub>D</sub>	Total Device Dissipation Derate above 25°C	625	mW
		5.0	mW/°C
R <sub>θJC</sub>	Thermal Resistance, Junction to Case	83.3	°C/W
R <sub>θJA</sub>	Thermal Resistance, Junction to Ambient	200	°C/W

# PNP General Purpose Amplifier

(continued)

BCX79

## Electrical Characteristics

TA = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
--------	-----------	-----------------	-----	-----	-------

### OFF CHARACTERISTICS

$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 10 \text{ mA}, I_B = 0$	45		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = 1.0 \mu\text{A}, I_C = 0$	5.0		V
$I_{CEX}$	Collector Cutoff Current	$V_{CE} = 45 \text{ V}, V_{BE} = 0.2 \text{ V}, T_A = +100 \text{ }^\circ\text{C}$		20	$\mu\text{A}$
$I_{CES}$	Collector Cutoff Current	$V_{CE} = 45 \text{ V}, I_E = 0, V_{CE} = 45 \text{ V}, I_E = 0, T_A = +125 \text{ }^\circ\text{C}$		10 2.5	nA $\mu\text{A}$
$I_{EBO}$	Emitter Cutoff Current	$V_{EB} = 4.0 \text{ V}, I_C = 0$		20	nA

### ON CHARACTERISTICS

$h_{FE}$	DC Current Gain	$V_{CE} = 5.0 \text{ V}, I_C = 2.0 \text{ mA}$ $V_{CE} = 1.0 \text{ V}, I_C = 10 \text{ mA}$ $V_{CE} = 1.0 \text{ V}, I_C = 100 \text{ mA}$	120 80 40	630 1,000	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 100 \text{ mA}, I_B = 2.5 \text{ mA}$		0.6	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 100 \text{ mA}, I_B = 2.5 \text{ mA}$		1.0	V
$V_{BE(on)}$	Base-Emitter On Voltage	$V_{CE} = 5.0 \text{ V}, I_C = 2.0 \text{ mA}$ $V_{CE} = 1.0 \text{ V}, I_C = 100 \text{ mA}$	0.6	0.7 0.9	V V

### SMALL SIGNAL CHARACTERISTICS

$C_{cb}$	Collector-Base Capacitance	$V_{CB} = 10 \text{ V}, f = 1.0 \text{ MHz}$		4.5	pF
$C_{eb}$	Emitter-Base Capacitance	$V_{EB} = 0.5 \text{ V}, f = 1.0 \text{ MHz}$		15	pF
$h_{ie}$	Input Impedance	$I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 1.0 \text{ kHz}$	1.6	8.5	k $\Omega$
$h_{oe}$	Output Admittance	$I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 1.0 \text{ kHz}$		100	$\mu\text{mhos}$
NF	Noise Figure	$V_{CE} = 5.0 \text{ V}, I_C = 0.2 \text{ mA}, R_S = 2.0 \text{ k}\Omega, f = 1.0 \text{ kHz}$		6.0	dB

### SWITCHING CHARACTERISTICS

$t_{on}$	Turn-on Time	$V_{CC} = 10 \text{ V}, I_C = 10 \text{ mA}, V_{BB} = 3.6 \text{ V}, I_{B1} = I_{B2} = 1.0 \text{ mA}$		150	ns
$t_{on}$	Turn-on Time	$V_{CC} = 10 \text{ V}, I_C = 100 \text{ mA}, V_{BB} = 5.0 \text{ V}, I_{B1} = I_{B2} = 10 \text{ mA}$		150	ns
$t_{off}$	Turn-off Time	$V_{CC} = 10 \text{ V}, I_C = 10 \text{ mA}, V_{BB} = 3.6 \text{ V}, I_{B1} = I_{B2} = 1.0 \text{ mA}$		800	ns
$t_{off}$	Turn-off Time	$V_{CC} = 10 \text{ V}, I_C = 100 \text{ mA}, V_{BB} = 5.0 \text{ V}, I_{B1} = I_{B2} = 10 \text{ mA}$		800	ns

## TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACE <sup>x</sup> <sup>TM</sup>	FAST <sup>r</sup> <sup>TM</sup>	PowerTrench <sup>®</sup>	SyncFET <sup>TM</sup>
Bottomless <sup>TM</sup>	GlobalOptoisolator <sup>TM</sup>	QFET <sup>TM</sup>	TinyLogic <sup>TM</sup>
CoolFET <sup>TM</sup>	GTO <sup>TM</sup>	QS <sup>TM</sup>	UHC <sup>TM</sup>
CROSSVOLT <sup>TM</sup>	HiSeC <sup>TM</sup>	QT Optoelectronics <sup>TM</sup>	VCX <sup>TM</sup>
DOME <sup>TM</sup>	ISOPLANAR <sup>TM</sup>	Quiet Series <sup>TM</sup>	
E <sup>2</sup> CMOS <sup>TM</sup>	MICROWIRE <sup>TM</sup>	SILENT SWITCHER <sup>®</sup>	
EnSigna <sup>TM</sup>	OPTOLOGIC <sup>TM</sup>	SMART START <sup>TM</sup>	
FACT <sup>TM</sup>	OPTOPLANAR <sup>TM</sup>	SuperSOT <sup>TM</sup> -3	
FACT Quiet Series <sup>TM</sup>	PACMAN <sup>TM</sup>	SuperSOT <sup>TM</sup> -6	
FAST <sup>®</sup>	POP <sup>TM</sup>	SuperSOT <sup>TM</sup> -8	

## DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

## LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

## PRODUCT STATUS DEFINITIONS

### Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

Rev. G